General purpose PIN diode

Rev. 01 — 26 May 2008

Product data sheet

1. Product profile

1.1 General description

Two planar PIN diodes in common anode configuration in a SOT323 small SMD plastic package.

1.2 Features

- Two elements in common anode configuration in a small SMD plastic package
- Low diode capacitance
- Low diode forward resistance

1.3 Applications

general RF application

2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	cathode 1	_	
2	cathode 2		
3	common connection	1 2 2	2 () 1 mgu320

3. Ordering information

Table 2. Ordering information

Type number	Package	Package				
	Name	Description	Version			
BAP51-06W	-	plastic surface-mounted package; 3 leads	SOT323			



4. Marking

Table 3. Marking		
Type number	Marking	Description
BAP51-06W	W7*	* = p: made in Hong Kong
		* = t : made in Malaysia

5. Limiting values

Table 4.	Limiting values
	Entrang raidoo

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V _R	reverse voltage		-	50	V
I _F	forward current		-	50	mA
P _{tot}	total power dissipation	$T_{sp} = 90 \ ^{\circ}C$	-	240	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

6. Thermal characteristics

Table 5.	Thermal characteristics					
Symbol	Parameter	Conditions	Тур	Unit		
R _{th(j-sp)}	thermal resistance from junction to solder point		250	K/W		

7. Characteristics

Table 6.Characteristics

 $T_i = 25 \circ C$ unless otherwise specified.

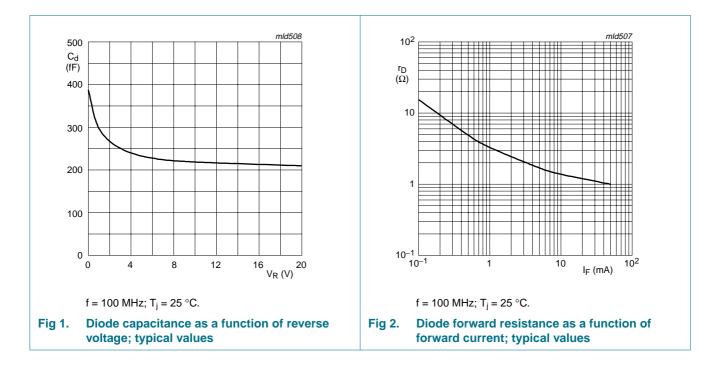
,	-					
Symbol	Parameter	Conditions	Mir	n Typ	Max	Unit
V_{F}	forward voltage	I _F = 50 mA	-	0.95	1.1	V
I _R	reverse current	V _R = 50 V	-	-	100	nA
C _d	diode capacitance	see Figure 1; f = 1 MHz				
		$V_R = 0 V$	-	0.4	-	pF
		$V_R = 1 V$	-	0.3	0.55	pF
		$V_R = 5 V$	-	0.2	0.35	pF
r _D	diode forward resistance	see Figure 2; f = 100 MHz				
		$I_{F} = 0.5 \text{ mA}$	<u>[1]</u> _	5.3	9	Ω
		$I_F = 1 \text{ mA}$	<u>[1]</u> _	3.5	6.5	Ω
		I _F = 10 mA	<u>[1]</u> -	1.5	2.5	Ω

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
ISL	isolation	V _R = 0 V				
		f = 900 MHz	-	17	-	dB
		f = 1800 MHz	-	13	-	dB
		f = 2450 MHz	-	12	-	dB
L _{ins}	insertion loss	I _F = 0.5 mA				
		f = 900 MHz	-	0.44	-	dB
		f = 1800 MHz	-	0.50	-	dB
		f = 2450 MHz	-	0.54	-	dB
		I _F = 1 mA				
		f = 900 MHz	-	0.33	-	dB
		f = 1800 MHz	-	0.39	-	dB
		f = 2450 MHz	-	0.43	-	dB
		I _F = 10 mA				
		f = 900 MHz	-	0.19	-	dB
		f = 1800 MHz	-	0.24	-	dB
		f = 2450 MHz	-	0.28	-	dB
τ _L	charge carrier life time	when switched from I_F = 10 mA to I_R = 6 mA; R _L = 100 Ω ; measured at I_R = 3 mA	-	0.55	-	μs
L _S	series inductance	I _F = 100 mA; f = 100 MHz	-	1.6	-	nH

Table 6 Characteristics aantin

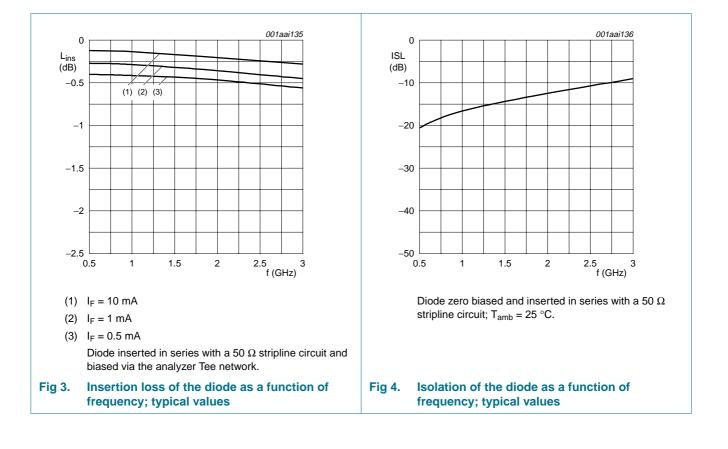
[1] Guaranteed on AQL basis: inspection level S4, AQL 1.0.



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BAP51-06W

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8. Package outline

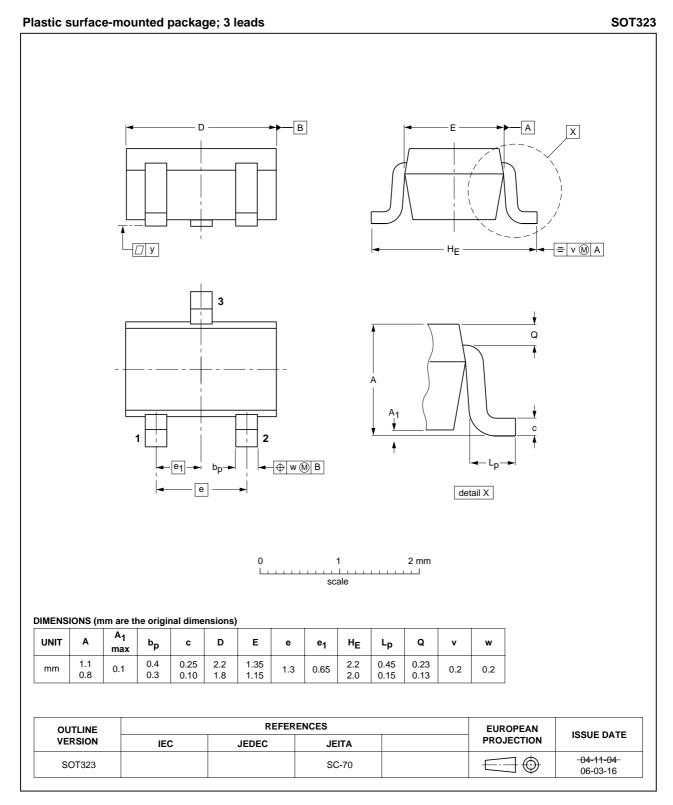


Fig 5.Package outline SOT323

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9. Abbreviations

Table 7. Ab	breviations
Acronym	Description
AQL	Acceptable Quality Level
PIN	P-type, Intrinsic, N-type
SMD	Surface Mounted Device
RF	Radio Frequency
S4	Special inspection level 4

10. Revision history

Table 8.	Revision history					
Documen	t ID	Release date	Data sheet status	Change notice	Supersedes	
BAP51-06	W_1	20080526	Product data sheet	-	-	

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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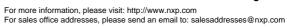
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